

20 V, 3.7 A / 320 mV VF P-channel MOSFET-Schottky combination

21 December 2012

Product data sheet

1. General description

Small-signal P-channel enhancement mode Field-Effect Transistor (FET) using Trench MOSFET technology and ultra low V_F Maximum Efficiency General Application (MEGA) Schottky diode combined in a small and leadless ultra thin DFN2020-6 (SOT1118) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- 1.8 V R_{DSon} rated for low-voltage gate drive
- Small and leadless ultra thin SMD plastic package: 2 × 2 × 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Integrated ultra low V_F MEGA Schottky diode

3. Applications

- Charging switch for portable devices
- DC-to-DC converters
- Power management in battery-driven portables
- · Hard disk and computing power management

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
MOSFET tra	nsistor		Ċ				
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-3.7	А
Schottky dic	ode				_		
l _F	forward current	T _{sp} ≤ 105 °C		-	-	2	А
V _R	reverse voltage	T _{amb} = 25 °C		-	-	20	V
MOSFET tra	nsistor static characteris	tics	·				
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -2.7 A; T _j = 25 °C		-	80	102	mΩ

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Schottky diode	Schottky diode						
V _F	forward voltage	I _F = 1 A; T _j = 25 °C		-	320	365	mV

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode	6 5 4	A G S
2	n.c.	not connected		
3	D	drain	7 8	
4	S	source		
5	G	gate		
6	к	cathode	Transparent top view DFN2020-6 (SOT1118)	K D aaa-003667
7	К	cathode	21112020 3 (0011110)	222-005007
8	D	drain		

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMFPB8032XP	DFN2020-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body $2 \times 2 \times 0.65$ mm	SOT1118				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMFPB8032XP	1X

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
MOSFET ti	ransistor					
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
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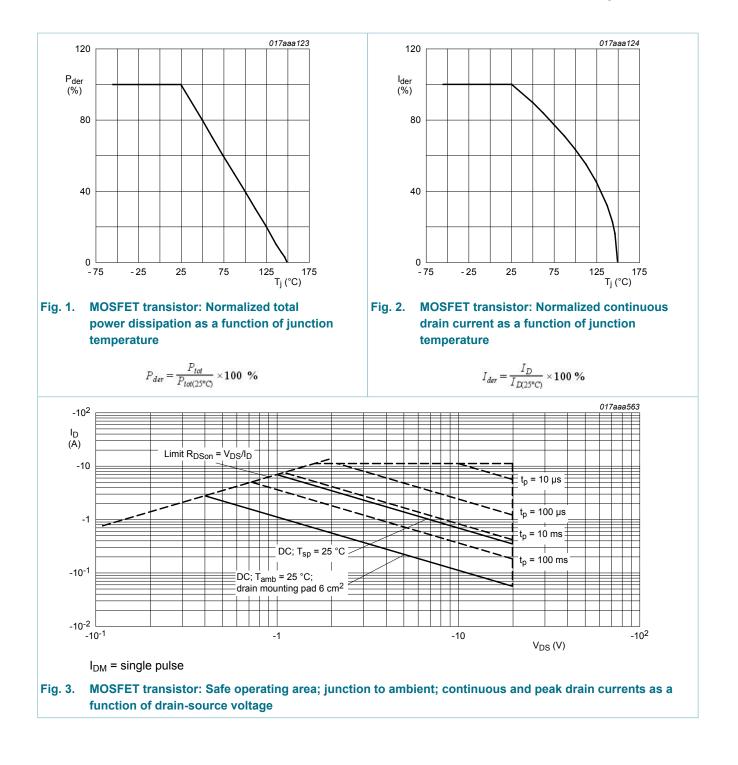
Symbol	Parameter	Conditions		Min	Max	Unit
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-3.7	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-2.7	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-1.7	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-11	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	485	mW
			[1]	-	1100	mW
		T _{sp} = 25 °C		-	6250	mW
Source-dra	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.1	А
Schottky d	iode					
V _R	reverse voltage	T _{amb} = 25 °C		-	20	V
l _F	forward current	T _{sp} ≤ 105 °C		-	2	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \delta \le 0.25; T_{amb} = 25 \text{ °C}$		-	7	А
I _{FSM}	non-repetitive peak forward	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	18	А
	current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; half-sine wave	[3]	-	25	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	480	mW
			[1]	-	1190	mW
		T _{sp} = 25 °C		-	6250	mW
Per device						_
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm². Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [1]

[2]

Calculated from square-wave measurements. [3]

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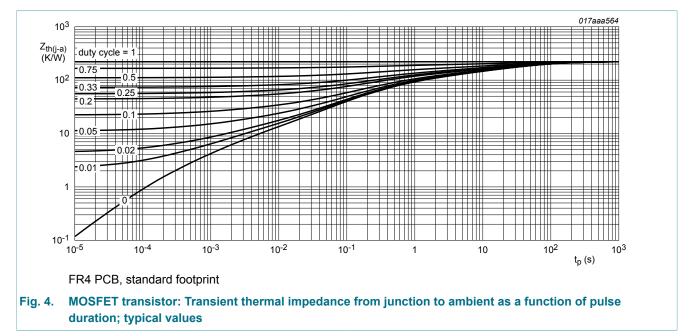


9. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
MOSFET tra	insistor						
R _{th(j-a)}	thermal resistance	in free air	[1]	-	225	260	K/W
	from junction to ambient		[2]	-	99	115	K/W
	ampient	in free air; t ≤ 5 s	[2]	-	54	62	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	16	20	K/W
Schottky die	ode	1					
R _{th(j-a)}	thermal resistance	in free air	[1]	-	-	260	K/W
.,	from junction to ambient		[2]	-	-	105	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

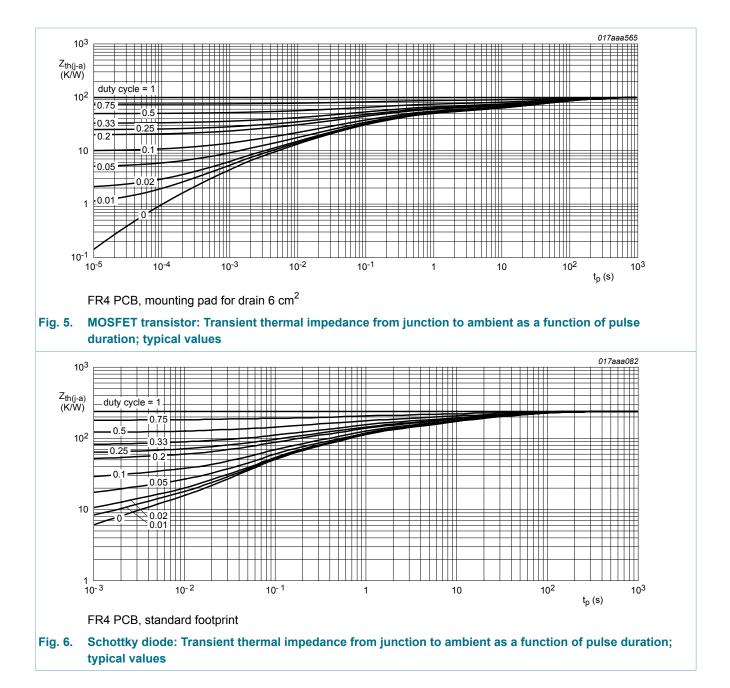
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

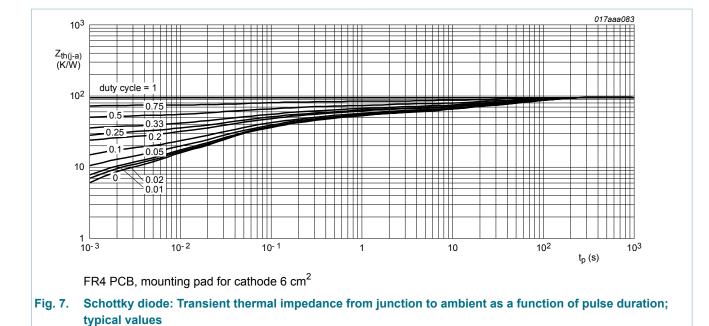
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
MOSFET tra	ansistor static characteris	tics				
V _{(BR)DSS}	drain-source breakdown voltage	I _D = -250 μA; V _{GS} = 0 V; T _j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.4	-0.6	-1	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{DS} = -20 V; V_{GS} = 0 V; T_j = 150 °C	-	-	-10	μA
I _{GSS}	gate leakage current	V_{GS} = -12 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
		V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -2.7 A; T _j = 25 °C	-	80	102	mΩ
		V _{GS} = -4.5 V; I _D = -2.7 A; T _j = 150 °C	-	116	148	mΩ
		V _{GS} = -2.5 V; I _D = -2.5 A; T _j = 25 °C	-	95	125	mΩ
		V _{GS} = -1.8 V; I _D = -1.1 A; T _j = 25 °C	-	120	156	mΩ
9 _{fs}	transfer conductance	V _{DS} = -10 V; I _D = -2.7 A; T _j = 25 °C	-	15	-	S
MOSFET tra	ansistor dynamic characte	ristics	I			
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -2.7 A; V _{GS} = -4.5 V;	-	5.7	8.6	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.7	-	nC
Q _{GD}	gate-drain charge		-	0.96	-	nC

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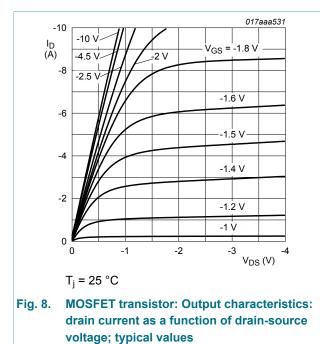
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	550	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	63	-	pF
C _{rss}	reverse transfer capacitance		-	53	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I_{D} = -2.4 A; V_{GS} = -4.5 V;	-	6	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	14	-	ns
t _{d(off)}	turn-off delay time	-	-	120	-	ns
t _f	fall time		-	50	-	ns
MOSFET tra	ansistor source-drain dio	de	I		1	
V _{SD}	source-drain voltage	I _S = -1.1 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.8	-1.2	V
Schottky di	iode					
V _F	forward voltage	I _F = 100 mA; T _j = 25 °C	-	225	275	mV
		I _F = 500 mA; T _j = 25 °C	-	285	335	mV
		I _F = 1 A; T _j = 25 °C	-	320	365	mV
I _R	reverse current	V _R = 5 V; T _j = 25 °C	-	65	220	μA
		V _R = 5 V; T _j = 125 °C	-	13	50	mA
		V _R = 10 V; T _j = 25 °C	-	110	400	μA
		V _R = 20 V; T _j = 25 °C	-	230	700	μA
C _d	diode capacitance	V _R = 5 V; f = 1 MHz; T _i = 25 °C	-	60	70	pF



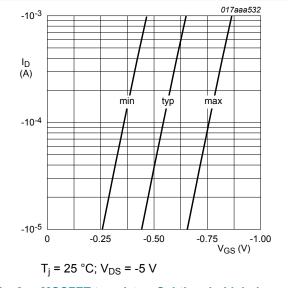
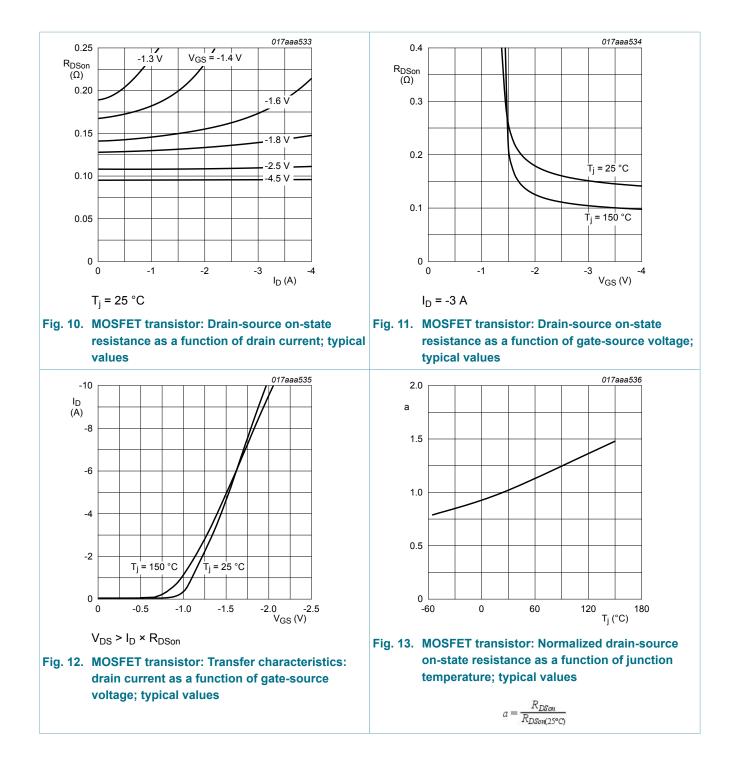


Fig. 9. MOSFET transistor: Subthreshold drain current as a function of gate-source voltage

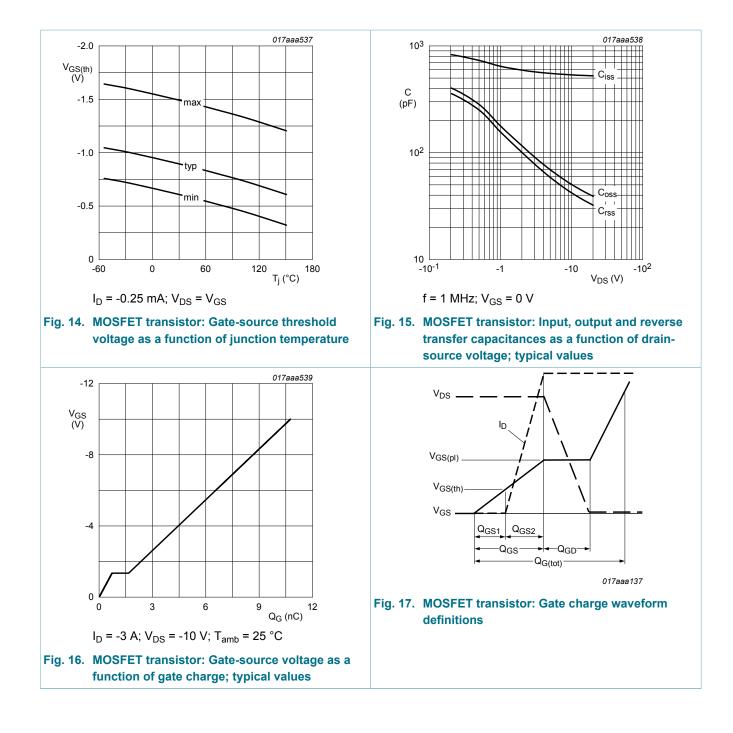
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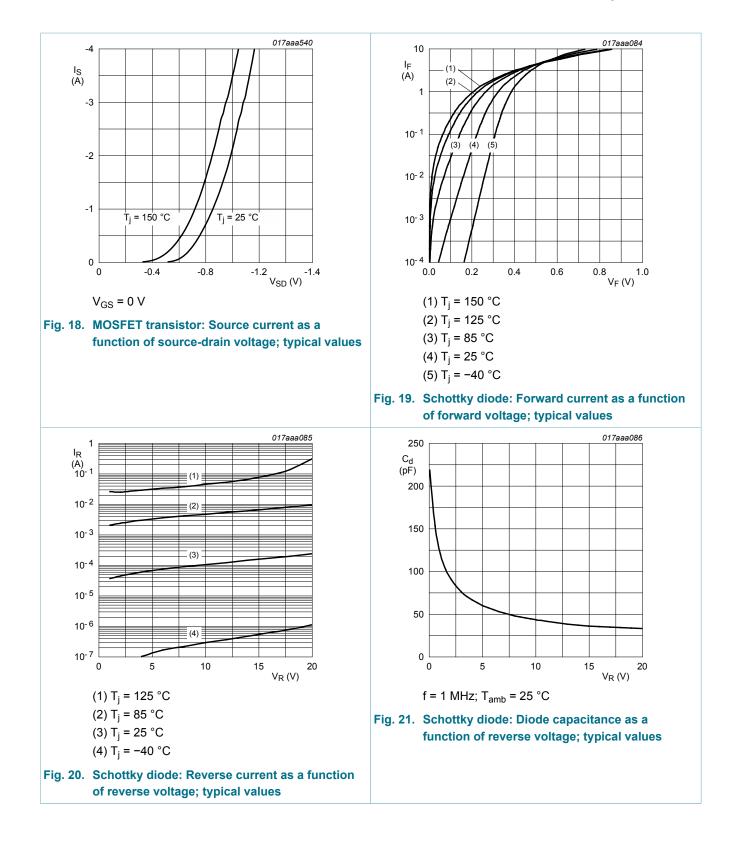


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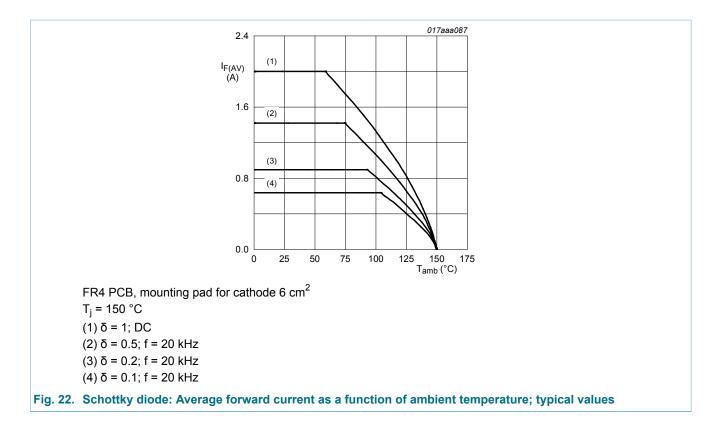
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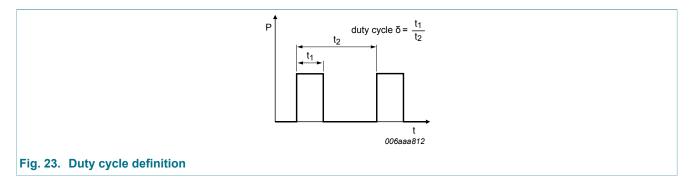
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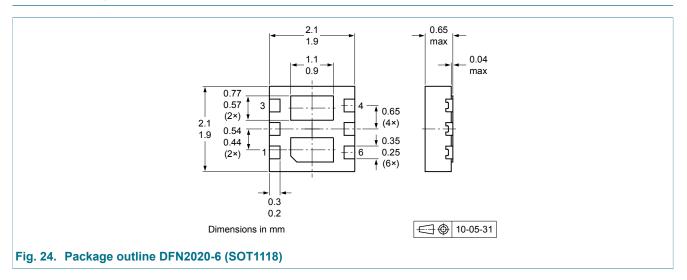
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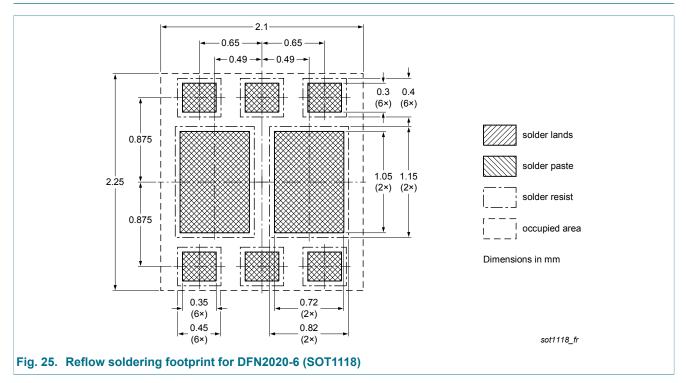
11. Test information



12. Package outline



13. Soldering



14. Revision history

Table 8. Revision hi	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMFPB8032XP v.1	20121221	Product data sheet	-	-
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